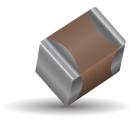
## **Y5V Dielectric General Specifications**





#### **GENERAL DESCRIPTION**

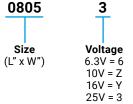
Y5V formulations are for general-purpose use in a limited temperature range. They have a wide temperature characteristic of +22% -82% capacitance change over the operating temperature range of -30°C to +85°C.

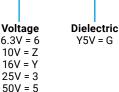
These characteristics make Y5V ideal for decoupling applications within limited temperature range.



### PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)

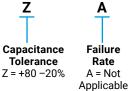
104





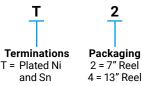
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	101
•	Capacitance Code (In pF) 2 Sig. Digits + Number of Zeros



Failure Rate A = Not

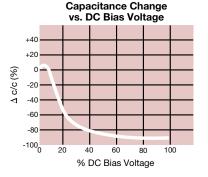
Α



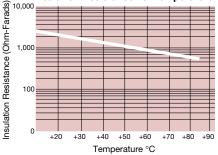
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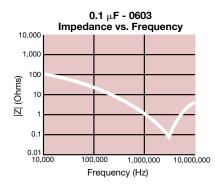


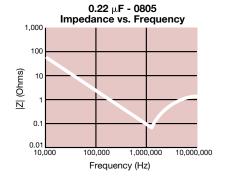
**Temperature Coefficient** +20 +10 0 % Δ Capacitance -10 -20 -30 -40 -50 -60 -70 -80 -35 -15 +5 +25 +45 +65 +85 +105 +125 -55 Temperature °C

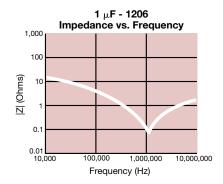


Insulation Resistance vs. Temperature 10,000











101316

# **Y5V Dielectric**



## **Specifications and Test Methods**

Parameter/Test		Y5V Specification Limits	Measuring Conditions					
Operating Tem		-30°C to +85°C	Temperature C	ycle Chamber				
Capac	itance	Within specified tolerance	-					
Dissipatio	on Factor	$\leq$ 5.0% for $\geq$ 50V DC rating $\leq$ 7.0% for 25V DC rating $\leq$ 9.0% for 16V DC rating $\leq$ 12.5% for $\leq$ 10V DC rating	Freq.: 1.0 kHz ± 10%   Voltage: 1.0Vrms ± .2V   For Cap > 10 μF, 0.5Vrms @ 120Hz   Charge device with rated voltage for 120 ± 5 secs   @ room temp/humidity   Charge device with 250% of rated voltage for 1-5 seconds, w/charge and discharge current limited to 50 mA (max)					
Insulation	Resistance	10,000MΩ or 500MΩ - μF, whichever is less						
Dielectric	Strength	No breakdown or visual defects						
	Appearance	No defects	Deflectio					
Resistance to	Capacitance Variation	≤ ±30%	Test Time: 3	30 seconds 7 1mm/sec				
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)						
	Insulation Resistance	≥ Initial Value x 0.1	90 1	mm				
Solder	ability	$\ge$ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.					
	Appearance	No defects, <25% leaching of either end terminal						
	Capacitance Variation	≤ ±20%						
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Dip device in eutectic solder at 260°C for 60 seconds. Store at room temperature for 24 ± 2 hours before measuring electrical properties.					
	Insulation Resistance	Meets Initial Values (As Above)						
	Dielectric Strength	Meets Initial Values (As Above)						
	Appearance	No visual defects	Step 1: -30°C ± 2°	30 ± 3 minutes				
	Capacitance Variation	≤ ±20%	Step 2: Room Temp	≤ 3 minutes				
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +85°C ± 2°	30 ± 3 minutes				
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes				
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles and measure after 24 ±2 hours at room temperature					
	Appearance	No visual defects	-					
	Capacitance Variation	≤ ±30%	Charge device with twic					
Load Life	Dissipation Factor	≤ Initial Value x 1.5 (See Above)	Remove from test chamber and stabilize at room temperature for 24 ± 2 hours before measuring.					
	Insulation Resistance	≥ Initial Value x 0.1 (See Above)						
	Dielectric Strength	Meets Initial Values (As Above)						
	Appearance	No visual defects	-					
	Capacitance Variation	≤ ±30%	Store in a test chamber set at 85°C ± 2°C/ 85% ± 5% relative humidity for 1000 hours					
Load Humidity	Dissipation Factor	≤ Initial Value x 1.5 (See above)	(+48, -0) with rated					
Taimaty	Insulation Resistance	≥ Initial Value x 0.1 (See Above)	Remove from chamber and stabilize at room temperature and humidity for					
	Dielectric Strength	Meets Initial Values (As Above)	24 ± 2 hours bef	ore measuring.				





### Capacitance Range

#### **PREFERRED SIZES ARE SHADED**

SIZE		02	01			0402			0603			0805			1206				1210					
Solderii	ng	Reflov	v Only		Ref	low/W	ave		F	Reflow/Wave			Reflow/Wave				ReflowMfeve				Reflow/Wave			e
Packagi	ng	All P	aper		A	II Pape	er			All P	aper		Paper/Embossed				Paper/Embossed				Paper/Embossed			sed
(L) Length	mm	0.60 ±	0.09		1.0	)0 ± 0.	10			1.60 :	± 0.15		2.01 ± 0.20			3.20 ± 0.20				3.20 ± 0.20				
(L) Length	(in.)	(0.024 ±				40 ± 0.			(0	(0.063 ± 0.006)			(0.079 ± 0.008)			(0.126 ± 0.008)				(0.126 ± 0.008)				
W) Width	mm	0.30 ±				50 ± 0.			.81 ± 0.15			1.25 ± 0.20				1.60 ± 0.20				2.50 ± 0.20				
m) main	(in.)	(0.011 ±		(0.020 ± 0.004)			(0.032 ± 0.006)			(0.049 ± 0.008)				(0.063 ± 0.008)				(0.098 ± 0.008)			8)			
(t) Terminal	mm	0.15 ±		0.25 ± 0.15			0.35 ± 0.15			0.50 ± 0.25			0.50 ± 0.25			.50 ± 0.25								
(1)	(in.)	(0.006 ±	,	(0.010 ± 0.006)		(0.014 ± 0.006)			(0.020 ± 0.010)			(0.020 ± 0.010)			(0.020 ± 0.010)									
Can	WVDC 820	63	10	6	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50
Сар	1000																			1	$\mathbf{x}$		-w	•
(pF)	2200		A																	<u> </u>	<	$\sim$	5	<
	4700		A																<u> </u>	(	5		$\mathcal{D}$	JT .
Сар	0.010	А	A																					
(μF)	0.010	A	A																		4			
(μι)	0.022	A				С																		, 1
	0.10	~			С	c					G	G				к								
	0.22				0					G	0	0				ĸ								
	0.33									G														
	0.47					С				G	G													
	1.0			С	С				G	G	J			N	Ν	N		М	М	М				Ν
	2.2				С				J					N	N				K	Q				
	4.7												Ν	Ν	Ν			Р	Q		1	Ν	Ν	
	10.0												Ν	Р			Q	Q	Х		Х	Q	Q	Z
	22.0																Q				Х	Z		
	47.0																							
0175	WVDC	63	10	6	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50
SIZE		02	01		0402			0603					08	05		1206				1210				

0.00 0.00 0.7	0.70	0.74	1.02	1.27	1.40	1.02	1.70	2.25	2.04	2.75
Letter   A   C   E     Max.   0.33   0.56   0.7	G	J	K	M	N	P	Q	X	Y	Z
	0.90	0.94	1.02	1 27	1.40	1.52	1.78	2.29	2.54	2.79



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